NSN 5961-01-029-5638



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-029-5638 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -90.0 breakdown voltage, collector-to-base, emitter open and -7.0 emitter to base voltage, static, collector open and -65.0 collector-to-emitter, substaining voltage, base open-circuited and -85.0 collector-to-emitter substaining voltage, resistance between base and emitter and -85.0 collector-to-emitter substaining voltage, with voltage between base and emitter **Current Rating Per Characteristic:** Between 0.50 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 7.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

Fiig:

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